BUK466-60A

GENERAL DESCRIPTION

QUICK REFERENCE DATA

N-channel enhancement mode field-effect power transistor in a plastic envelope suitable for surface mount applications.

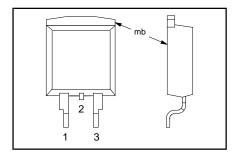
applications.
The device is intended for use in Switched Mode Power Supplies (SMPS), motor control, welding, DC/DC and AC/DC converters, and in automotive and general purpose switching applications.

SYMBOL	PARAMETER	MAX.	UNIT
V _{DS} I _D P _{tot} T _j R _{DS(ON)}	Drain-source voltage Drain current (DC) Total power dissipation Junction temperature Drain-source on-state resistance	60 52 150 175 0.028	> A

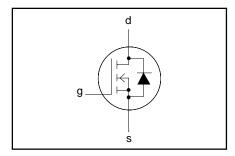
PINNING - SOT404

PIN	DESCRIPTION	
1	gate	
2	drain	
3	source	
mb	drain	

PIN CONFIGURATION



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{DS}	Drain-source voltage	- 00 I-O	-	60	V
V _{DGR} ±V _{GS}	Drain-gate voltage Gate-source voltage	$R_{GS} = 20 \text{ k}\Omega$	-	60 30	V
I _D	Drain current (DC)	$T_{mb} = 25 \degree C$	-	52	A
I _D I _{DM}	Drain current (DC) Drain current (pulse peak value)	T _{mb} = 100 °C T _{mb} = 25 °C	-	36 208	l A A
P _{tot}	Total power dissipation	$T_{mb} = 25 \degree C$	-	150	W
T _{stg}	Storage temperature	-	- 55	175	.c
l I j	Junction temperature	-	-	175	'

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-mb}	Thermal resistance junction to mounting base		-	-	1.0	K/W
R _{th j-a}	Thermal resistance junction to ambient	minimum footprint, FR4 board (see Fig 18).	-	50	-	K/W

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STATIC CHARACTERISTICS

 T_{mb} = 25 °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_{(BR)DSS}$	Drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_{D} = 0.25 \text{ mA}$	60	-	-	V
$V_{\text{GS(TO)}} \\ I_{\text{DSS}} \\ I_{\text{DSS}} \\ I_{\text{GSS}} \\ R_{\text{DS(ON)}}$	Gate threshold voltage	$\begin{array}{l} V_{DS} = V_{GS}; \ I_D = 1 \ mA \\ V_{DS} = 60 \ V; \ V_{GS} = 0 \ V; \ T_j = 25 \ ^{\circ}C \\ V_{DS} = 60 \ V; \ V_{GS} = 0 \ V; \ T_j = 125 \ ^{\circ}C \\ V_{GS} = \pm 30 \ V; \ V_{DS} = 0 \ V \\ V_{GS} = 10 \ V; \ I_D = 29 \ A \end{array}$	2.1 - - - -	3.0 1 0.1 10 0.024	4.0 10 1.0 100 0.028	V μA mA nA

DYNAMIC CHARACTERISTICS

Tmb = 25 °C unless otherwise specified

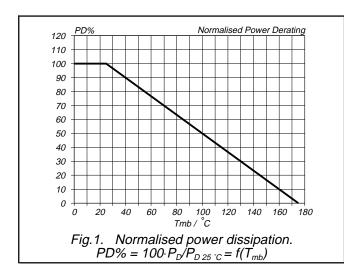
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
g _{fs}	Forward transconductance	$V_{DS} = 25 \text{ V}; I_{D} = 29 \text{ A}$	17	22	1	Ø
C _{iss} C _{oss} C _{rss}	Input capacitance Output capacitance Feedback capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 25 \text{ V}; f = 1 \text{ MHz}$		1500 800 270	2000 1000 400	pF pF pF
$t_{d \text{ on}}$ t_{r} $t_{d \text{ off}}$ t_{f}	Turn-on delay time Turn-on rise time Turn-off delay time Turn-off fall time	$V_{DD} = 30 \text{ V}; I_{D} = 3 \text{ A}; \ V_{GS} = 10 \text{ V}; \ R_{GS} = 50 \Omega; \ R_{gen} = 50 \Omega$	1 1 1 1	20 70 170 120	30 100 220 160	ns ns ns ns
L _d L _s	Internal drain inductance Internal source inductance	Measured from upper edge of drain tab to centre of die Measured from source lead soldering point to source bond pad		2.5 7.5	1 1	nH nH

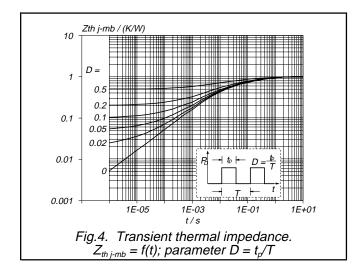
REVERSE DIODE LIMITING VALUES AND CHARACTERISTICS

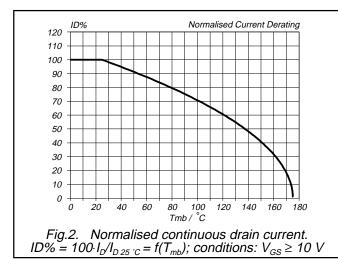
Tmb = 25 °C unless otherwise specified

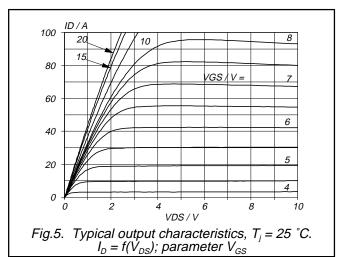
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{DR}	Continuous reverse drain current	-	-	-	52	Α
$egin{array}{c} oldsymbol{I_{DRM}} \ oldsymbol{V_{SD}} \end{array}$	Pulsed reverse drain current Diode forward voltage	$I_F = 52 \text{ A}$; $V_{GS} = 0 \text{ V}$		- 1.8	208 2.5	A V
t _{rr} Q _{rr}	Reverse recovery time Reverse recovery charge	$I_F = 52 \text{ A}; -dI_F/dt = 100 \text{ A/}\mu\text{s};$ $V_{GS} = 0 \text{ V}; V_R = 30 \text{ V}$	-	80 0.4		ns μC

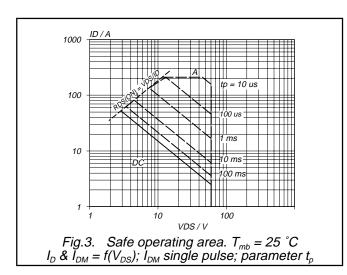
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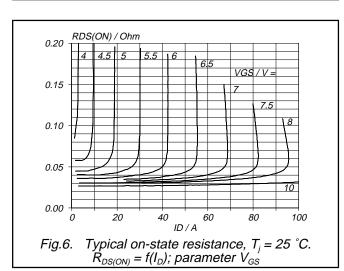




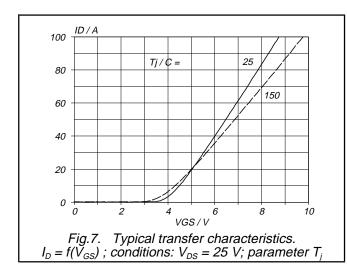


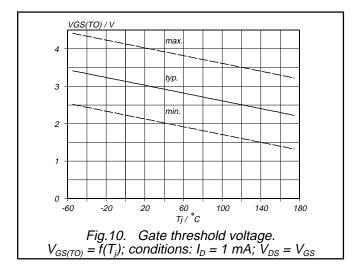


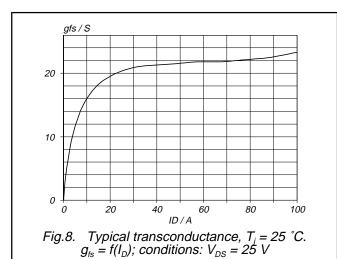


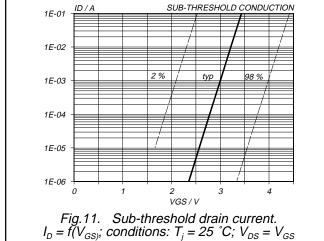


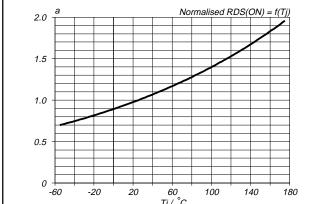
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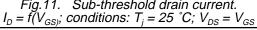


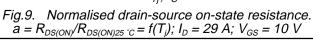


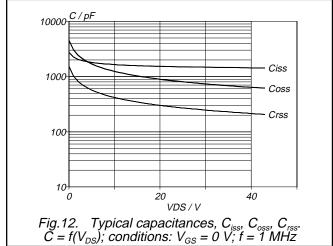












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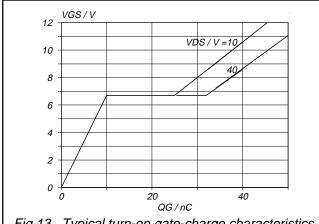


Fig.13. Typical turn-on gate-charge characteristics. $V_{GS} = f(Q_G)$; conditions: $I_D = 52$ A; parameter V_{DS}

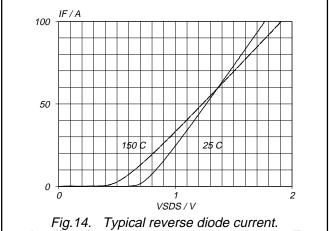
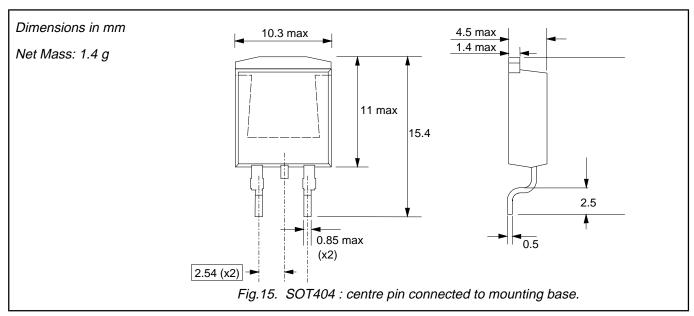


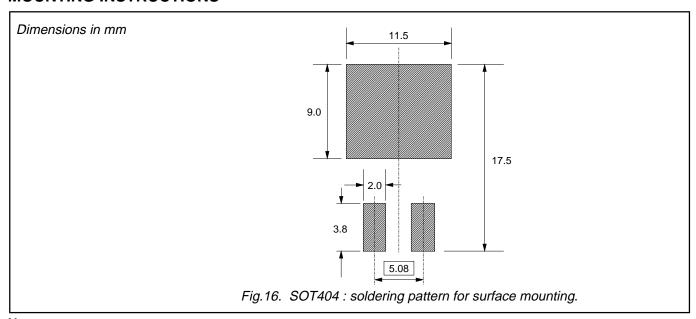
Fig.14. Typical reverse diode current. $I_F = f(V_{SDS})$; conditions: $V_{GS} = 0$ V; parameter T_j

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MECHANICAL DATA



MOUNTING INSTRUCTIONS



Notes

- Observe the general handling precautions for electrostatic-discharge sensitive devices (ESDs) to prevent damage to MOS gate oxide.
 Epoxy meets UL94 V0 at 1/8".

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DEFINITIONS

Data sheet status				
Objective specification	This data sheet contains target or goal specifications for product development.			
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.			
Product specification	This data sheet contains final product specifications.			

Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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